



DMN1150UFB

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on) max}	Ι _D T _A = +25°C
	0.15Ω @ V _{GS} = 4.5V	1.41A
12V	0.185Ω @ V _{GS} = 2.5V	1.25A
	0.21Ω @ V _{GS} = 1.8V	1.16A

Description

This new generation MOSFET has been designed to minimize the onstate resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Power management functions

Features

- Low On-Resistance
- Very Low Gate Threshold Voltage VGS(TH), 1.0V max
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: X1-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208 @4

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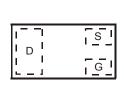
Weight: 0.001 grams (approximate)

X1-DFN1006-3





Bottom View



Top View Internal Schematic

Drain Body Diode Gate Gate Protection Source Diode

Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN1150UFB-7B	X1-DFN1006-3	10,000/Tape & Reel

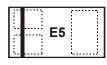
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. Notes:

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



E5 = Product Type Marking Code Bar Denotes Gate and Source Side

Top View



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	12	V
Gate-Source Voltage			V _{GSS}	±6	V
Continuous Drain Current (Note 5) V _{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	1.41 1.15	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	7	А
Maximum Body Diode continuous Current			Is	1	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Total Dower Dissinction (Note 5)	T _A = +25°C	D	0.5	10/	
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.3	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	$R_{\theta JA}$	251	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

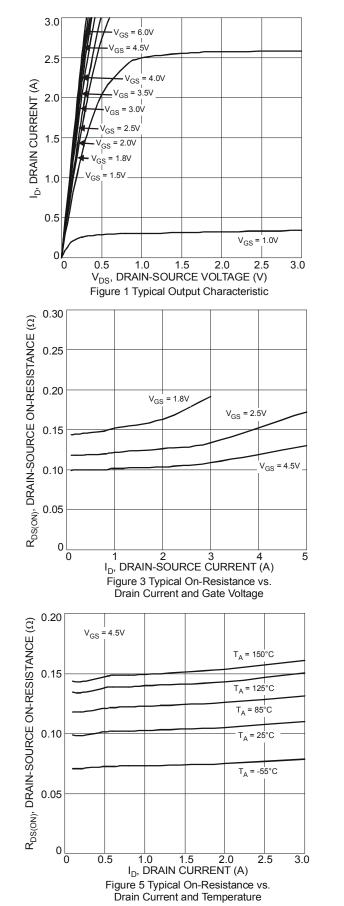
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

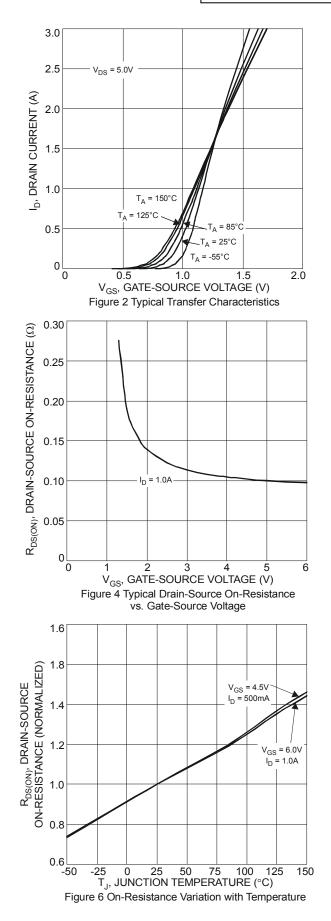
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV _{DSS}	12	_		V	V _{GS} = 0V, I _D = 250µA	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}		_	100	nA	$V_{DS} = 12V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		_	±1	μA	V_{GS} = ±6V, V_{DS} = 0V	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V _{GS(th)}	0.35	—	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
			—	150		V _{GS} = 4.5V, I _D = 1A	
Static Drain-Source On-Resistance	R _{DS (ON)}	—	—	185	mΩ	V _{GS} = 2.5V, I _D = 1A	
			_	210		V _{GS} = 1.8V, I _D = 1A	
Diode Forward Voltage	V _{SD}		0.7	1.2	V	V _{GS} = 0V, I _S = 150mA	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss		106		pF		
Output Capacitance	Coss		23		pF	V _{DS} =10V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss		21		pF	1 - 1.00012	
Gate resistance	R _g		92.4		Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1.0MHz	
Total Gate Charge (V _{GS} = 4.5V)	Qg		1.5		nC	V _{DS} = 4V, I _D = 1A	
Gate-Source Charge	Q _{gs}		0.2		nC		
Gate-Drain Charge	Q _{gd}		0.2		nC		
Turn-On Delay Time	t _{D(on)}		4.1		ns		
Turn-On Rise Time	tr		34.5		ns	$V_{DD} = 4V, V_{GS} = 6V, I_D = 1A$	
Turn-Off Delay Time	t _{D(off)}		57		ns	R _G = 1Ω	
Turn-Off Fall Time	t _f		30		ns	7	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



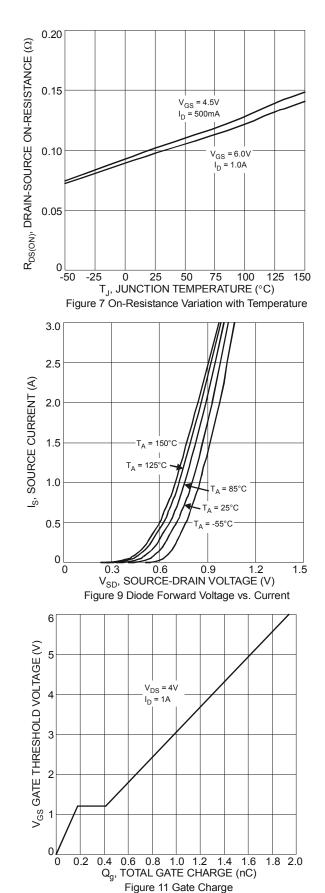
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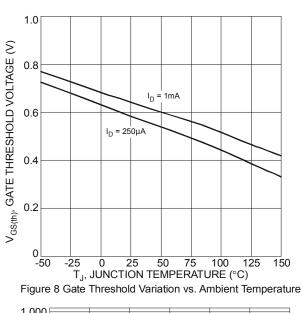


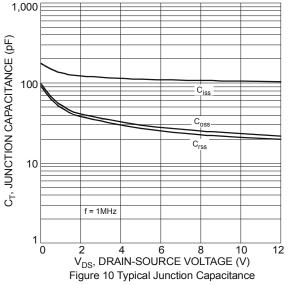


NEW PRODUCT



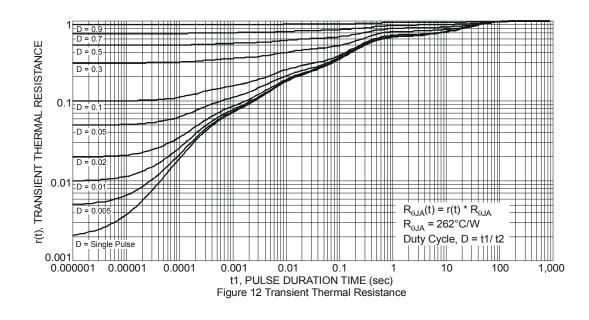






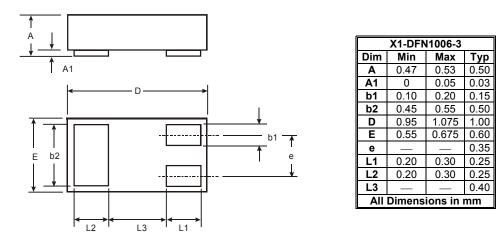
NEW PRODUCT





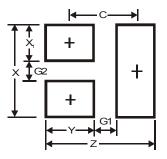
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	1.1
G1	0.3
G2	0.2
Х	0.7
X1	0.25
Y	0.4
С	0.7



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